

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	17425	((resist photoresist) same (etch\$3 remov\$3) same temperature) and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/03 10:35
L3	368	2 and (etch\$3 remov\$3) with temperature near7 (room "30" "40" "50") same plasma	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/03 10:37
L4	8	3 and (etch\$3 remov\$3) same (flouride floride (flouro floro) adj carb\$3 c near3 f) same plasma	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/03 10:47
L6	8	4 not (@rlad>"20040930" @ad>"20040930")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/03 10:59
L7	8	6 and (flouride floride (flouro floro) adj carb\$3 c near3 f)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/03 10:54
L8	6	(3 not 6) and (etch\$3 remov\$3) same (flouride floride (flouro floro) adj carb\$3 c near3 f)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/03 10:48
L9	6	8 and (flouride floride (flouro floro) adj carb\$3 c near3 f)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/03 10:48
L10	78	3 and (fluorinated near carbon "f.sub.2" "f.sub.3" "f.sub.4" "f.sub.6" cf4 ch2f2 chf3 c2f6 c near3 f)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/03 10:58
L11	78	10 and (fluorinated near carbon "f.sub.2" "f.sub.3" "f.sub.4" "f.sub.6" cf4 ch2f2 chf3 c2f6 c near3 f)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/03 10:58
L12	78	11 not (@rlad>"20040930" @ad>"20040930")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/03 10:59